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National Semiconductor

## 54LVX3383 10-Bit Low Power Bus-Exchange Switch

### **General Description**

The 54LVX3383 provides two sets of high-speed CMOS TTL-compatible bus switches. The low on resistance of the switch allows inputs to be connected to outputs without adding propagation delay or generating additional ground bounce noise. The device operates as a 10-bit bus switch or a 5-bit bus exchanger. The bus exchange (BX) signal provides nibble swapping of the AB and CD pairs of signals. This exchange configuration allows byte swapping of buses in systems. It can also be used as a quad 2-to-1 multiplexer and to create low delay barrel shifters. The bus enable  $(\overline{\text{BE}})$  signal turns the switches on.

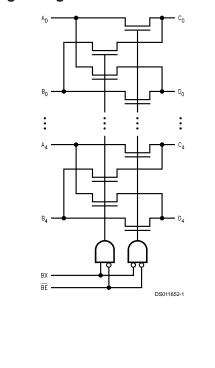
## Features

- 5Ω switch connection between two ports
- Minimal propagation delay through the switch
- Ultra low power with 0.2 µA typical I<sub>CC</sub>
- Zero ground bounce in flow-through mode
- Control inputs compatible with TTL level
- Available in CDIP and Flatpack packages
- Standard Microcircuit Drawing (SMD) 5962-9950601

## **Ordering Code**

Order Number	Package Number	Package Description	
54LVX3383J-QML	J24F	24-Lead Ceramic Dual-in-line	
54LVX3383W-QML	W24C	24-Lead Cerpack	

## Logic Diagram



## **Connection Diagram**



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## **Pin Descriptions**

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Pin Names		Names	Description		
BE			Bus Switch Enable		
BX			Bus Exchange		
A <sub>0</sub> -A <sub>4</sub> , B <sub>0</sub> -B <sub>4</sub>		-B <sub>4</sub>	Buses A, B		
C <sub>0</sub> -C <sub>4</sub> , D <sub>0</sub> -D <sub>4</sub>		<sub>0</sub> -D <sub>4</sub>	Buses C, D		
BE	ΒХ	A <sub>0</sub> -A <sub>4</sub>	B <sub>0</sub> -B <sub>4</sub>	Function	
н	Х	High-Z State	High-Z State	Disconnect	
L	L	C <sub>0</sub> -C <sub>4</sub>	D <sub>0</sub> - D <sub>4</sub>	Connect	
L	Н	D <sub>0</sub> -D <sub>4</sub>	C <sub>0</sub> -C <sub>4</sub>	Exchange	

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## Absolute Maximum Ratings (Note 1)

If Military/Aerospace specified devices are required, please contact the National Semiconductor Sales Office/ Distributors for availability and specifications.

Supply Voltage (V <sub>CC</sub> )	-0.5V to +7.0V
DC Switch Voltage (V <sub>S</sub> )	-0.5V to +7.0V
DC Input Voltage (VI) (Note 2)	-0.5V to +7.0V
DC Input Diode Current ( $I_{IN}$ ) with $V_I < 0$	–20 mA
DC Output (I <sub>O</sub> ) Sink Current	30 mA
Storage Temperature Range (T <sub>STG</sub> )	-65°C to +150°C
Junction Temperature (T <sub>J</sub> )	175°C
Power Dissipation	500mW

**DC Electrical Characteristics** 

# Recommended Operating Conditions

Supply Voltage (V <sub>CC</sub> )	4.5V to 5.5V
Input Voltage (V <sub>IN</sub> )	0V to 5.5V
Input Rise and Fall Time (tr, t <sub>f</sub> )	
Switch Control Input	0ns/V to 8ns/V
Switch I/O	0ns/V to DC
Free Air Operating Temperature (T <sub>A</sub> )	–55°C to +125°C

Note 1: The "Absolute Maximum Ratings" are those values beyond which the safety of the device cannot be guaranteed. The device should not be operated at these limits. The parametric values defined in the Electrical Characteristics tables are not guaranteed at the absolute maximum ratings. The "Recommended Operating Conditions" table will define the conditions for actual device operation.

**Note 2:** The input and output negative voltage ratings may be exceeded if the input and output diode current ratings are observed.

#### $T_A = -55^{\circ}C$ to Symbol Parameter $V_{cc}$ Units Conditions (V) +125°C Min Max VIK Maximum Clamp 4.5 -1.2 V $I_{IN} = -18 \text{ mA}$ Diode Voltage V $V_{\rm IH}$ Minimum High 4.5-5.5 2.0 Level Input Voltage $V_{\rm IL}$ 4.5-5.5 0.8 Maximum Low Level Input Voltage Maximum Input 0 10 μΑ $0 \leq V_{IN} \leq 5.5 V$ $I_{IN}$ Leakage Current 5.5 ±1 Maximum TRI-STATE 5.5 ±10 μA $0 \leq A, \ B \leq V_{CC}$ $I_{OZ}$ I/O Leakage $V_{I} = 0V, I_{ON} = 30 \text{ mA}$ 4.5 10 $R_{ON}$ Switch On Ω Resistance (Note 3) $V_I$ = 2.4V, $I_{ON}$ = 15 mA 20 Ω $V_I = V_{CC}$ , GND $I_{CC}$ Maximum Quiescent 5.5 10 μΑ Supply Current $I_{O} = 0$ Increase in I<sub>cc</sub> 5.5 2.5 mΑ $V_{IN} = 3.15V, I_O = 0$ $\Delta I_{\rm CC}$ per Input (Note 4) Per Control Input

Note 3: Measured by voltage drop between A and B pin at indicated current through the switch. On resistance is determined by the lower of the voltages on the two (A or B) pins.

Note 4: Per TTL driven input ( $V_{IN}$  = 3.15V, control inputs only). A and B pins do not contribute to I<sub>CC</sub>.

Symbol	Parameter	V <sub>cc</sub> (V)	$T_A = -55^{\circ}C \text{ to } +125^{\circ}C$ $C_L = 50 \text{ pF}$		Units
			Min	Max	
PLH,	Data Propagation Delay	4.5-5.5		0.25	ns
PHL	$A_n$ to $C_n$ , $D_n$ or $B_n$ to $D_n$ , $C_n$ (Note 6)				
PLH,	Switch Exchange Time	4.5-5.5	1.5	7.0	ns
PHL	BX to $A_n$ , $B_n$ , $C_n$ , $D_n$				
PZL,	Switch Enable Time	4.5-5.5	1.5	7.0	ns
PZH	$\overline{BE}$ to $A_{n}, B_{n}, C_{n}$ or $D_{n}$				
PLZ,	Switch Disable Time	4.5-5.5	1.5	7.0	ns
t <sub>PHZ</sub>	$\overline{BE}$ to $A_{n}, B_{n}, C_{n}$ , or $D_{n}$				

Note 5: All typical values are at V\_{CC} = 5.0V, T\_A = 25  $^\circ\text{C}.$ 

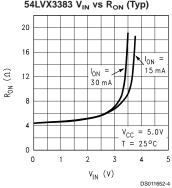
Note 6: This parameter is guaranteed by design but not tested. The bus switch contributes no propagation delay other than the RC delay of the On resistance of the switch and the load capacitance. The time constant for the switch and alone is of the order of 0.25 ns for 50 pF load. Since this time constant is much smaller than the rise/fall times of typical driving signals, it adds very little propagation delay to the system. Propagation delay of the bus switch when used in a system is determined by the driving circuit on the driving side of the switch and its interaction with the load on the driven side.

## Capacitance (Note 7)

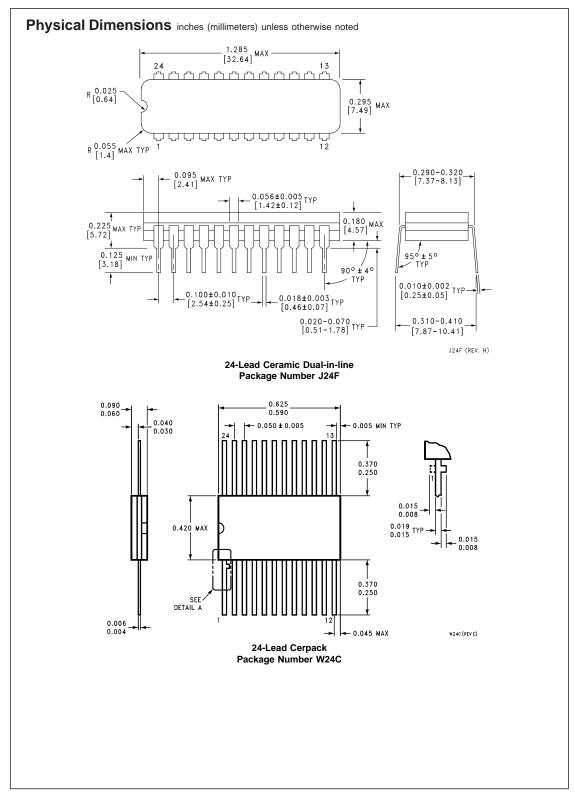
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Symbol	Parameter	Max	Units	Conditions
C <sub>IN</sub>	Control Input Capacitance	12	pF	$V_{CC} = 5.0V$
C <sub>I/O</sub> (OFF)	Input/Output Capacitance	20	pF	$V_{CC} = 5.0V$

Note 7: Capacitance is characterized but not tested.



54LVX3383  $V_{\rm IN}$  vs  $R_{\rm ON}$  (Typ)



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Notes

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